

Supplemental Amendment  
Takashi KANO et al.

U.S. Patent Application S.N. 09/532,775  
Attorney Docket No. 000352

**REMARKS**

If, for any reason, it is felt that this application is not now in condition for allowance, the Examiner is requested to contact Applicants undersigned attorney at the telephone number indicated below to arrange for an interview to expedite the disposition of this case.

Attached hereto is a marked-up version of the changes made to the by the current amendment. The attached page is captioned "Version with markings to show changes made."

In the event that this paper is not timely filed, Applicants respectfully petitions for an appropriate extension of time. Please charge any fees for such an extension of time and any other fees which may be due with respect to this paper, to Deposit Account No. 01-2340.

Respectfully submitted,

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Enclosures: Version with markings to show changes made  
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**VERSION WITH MARKINGS TO SHOW CHANGES MADE**

**IN THE CLAIMS:**

Please amend claim 3 as follows:

3. (Twice Amended) The semiconductor laser device according to claim 1, wherein  
said first nitride based semiconductor layer further includes [a] said second conductivity type  
cladding layer provided between said active layer and a [second conductivity type] second  
conductivity type cladding layer in said second nitride based semiconductor layer.